## NSN 5962-01-087-5973

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view Online at https://aerobasegroup.com/nsn/5962-01-067-5973
Body Length:
Between 0.745 inches and 0.785 inches
Body Width:
Between 0.240 inches and 0.260 inches
Body Height:
Between 0.105 inches and 0.180 inches
Maximum Power Dissipation Rating:
480.0 milliwatts
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar and monolithic and positive outputs and w/enable and 3-state output and w/disable and programmable and programmed and
schottky and expandable and w/decoded output and w/buffered output
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Case Outline Source And Designator:
-0-001-ac joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
55760-100136 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit

N/a

Shelf Life:

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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